# mail

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## **Digital Transistors (BRT)** R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

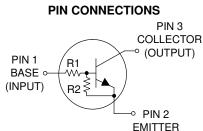
Rating	Symbol	Max	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	100	mAdc
Input Forward Voltage	V <sub>IN(fwd)</sub>	40	Vdc
Input Reverse Voltage	V <sub>IN(rev)</sub>	10	Vdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

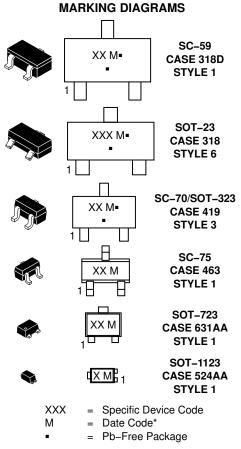


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(GROUND)



(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

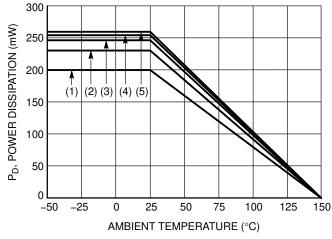
See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

#### Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping <sup>†</sup>
MUN2237T1G, NSVMUN2237T1G*	8P	SC–59 (Pb–Free)	3000 / Tape & Reel
MMUN2237LT1G, NSVMMUN2237LT1G*	AA3	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5237T1G	8P	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTC144WET1G, NSVDTC144WET1G*	8P	SC-75 (Pb-Free)	3000 / Tape & Reel
DTC144WM3T5G	8P	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSBC144WF3T5G	Q	SOT-1123 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.



SC-75 and SC-70/SOT323; Minimum Pad
 SC-59; Minimum Pad
 SOT-23; Minimum Pad
 SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace
 SOT-723; Minimum Pad

Figure 1. Derating Curve

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SC-59) (MUN2237)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 1) (Note 2) (Note 1)	P <sub>D</sub>	230 338 1.8	mW mW/°C
Thermal Resistance,	(Note 2) (Note 1)	$R_{\thetaJA}$	2.7 540	°C/W
Junction to Ambient Thermal Resistance,	(Note 2) (Note 1)	$R_{\thetaJL}$	370 264	°C/W
Junction to Lead Junction and Storage Temperature Range	(Note 2)	T <sub>J</sub> , T <sub>stg</sub>	287 -55 to +150	°C
THERMAL CHARACTERISTICS (SOT-23) (MMUN2237L)		'J, 'stg	-33 10 + 130	0
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	(Note 1) (Note 2) (Note 1) (Note 2)	P <sub>D</sub>	246 400 2.0 3.2	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	508 311	°C/W
Thermal Resistance, Junction to Lead	(Note 1) (Note 2)	$R_{ ext{ heta}JL}$	174 208	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5237)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 1) (Note 2) (Note 1) (Note 2)	P <sub>D</sub>	202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	618 403	°C/W
Thermal Resistance, Junction to Lead	(Note 1) (Note 2)	$R_{\thetaJL}$	280 332	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-75) (DTC144WE)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	(Note 1) (Note 2) (Note 1) (Note 2)	P <sub>D</sub>	200 300 1.6 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	600 400	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SOT-723) (DTC144WM3)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 1) (Note 2) (Note 1) (Note 2)	P <sub>D</sub>	260 600 2.0 4.8	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\thetaJA}$	480 205	°C/W
Junction and Storage Temperature Range	. ,	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

2. FR-4 @ 1.0 x 1.0 Inch Pad. 3. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air. 4. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBC144WF3)			•	
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 3) (Note 4) (Note 3) (Note 4)	PD	254 297 2.0 2.4	m₩ mW/°C
Thermal Resistance, Junction to Ambient	(Note 3) (Note 4)	$R_{\theta JA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 3)	$R_{ ext{ heta}JL}$	193	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

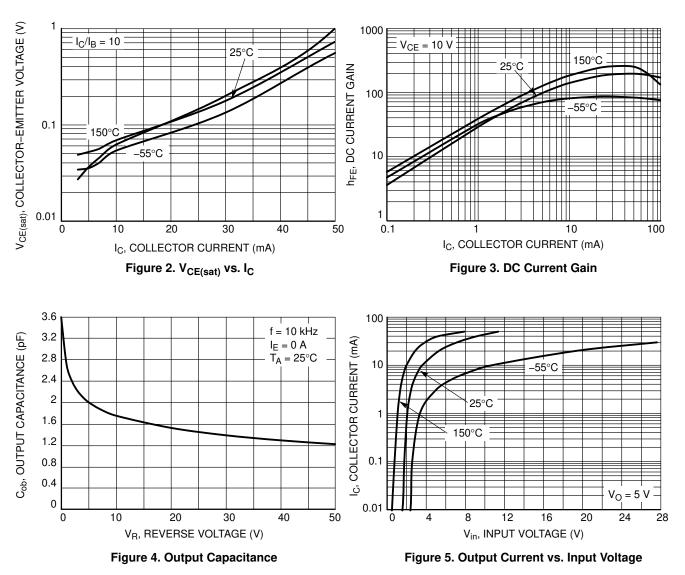
1. FR-4 @ Minimum Pad.

2. FR-4 @ 1.0 x 1.0 lnch Pad. 3. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air. 4. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

#### Table 3. ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = $25^{\circ}$ C, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Base Cutoff Current $(V_{CB} = 50 \text{ V}, I_E = 0)$	Ісво	-	-	100	nAdc
Collector–Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	ICEO	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_{C} = 0$ )	I <sub>EBO</sub>	-	_	0.13	mAdc
Collector–Base Breakdown Voltage ( $I_C = 10 \ \mu A, I_E = 0$ )	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector–Emitter Breakdown Voltage (Note 5) $(I_C = 2.0 \text{ mA}, I_B = 0)$	V <sub>(BR)CEO</sub>	50	_	-	Vdc
ON CHARACTERISTICS					
DC Current Gain (Note 5) ( $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$ )	h <sub>FE</sub>	80	140	-	
Collector – Emitter Saturation Voltage (Note 5) $(I_C = 10 \text{ mA}, I_B = 5.0 \text{ mA})$	VCE(sat)	-	_	0.25	Vdc
Input Voltage (off) ( $V_{CE} = 5.0 \text{ V}, I_C = 100 \mu \text{A}$ )	V <sub>i(off)</sub>	_	1.8	1.2	Vdc
Input Voltage (on) ( $V_{CE} = 0.3 \text{ V}, I_C = 2.0 \text{ mA}$ )	V <sub>i(on)</sub>	4.0	2.3	-	Vdc
Output Voltage (on) $(V_{CC} = 5.0 \text{ V}, V_B = 4.0 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	V <sub>OL</sub>	_	-	0.2	Vdc
Output Voltage (off) $(V_{CC} = 5.0 \text{ V}, \text{ V}_{B} = 0.25 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega)$	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor	R1	32.9	47	61.1	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	1.7	2.1	2.6	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .



TYPICAL CHARACTERISTICS MUN2237, MMUN2237L, MUN5237, DTC144WE, DTC144WM3

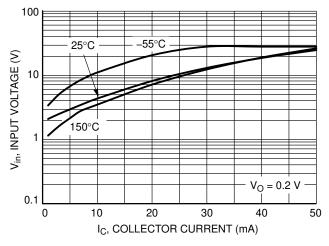
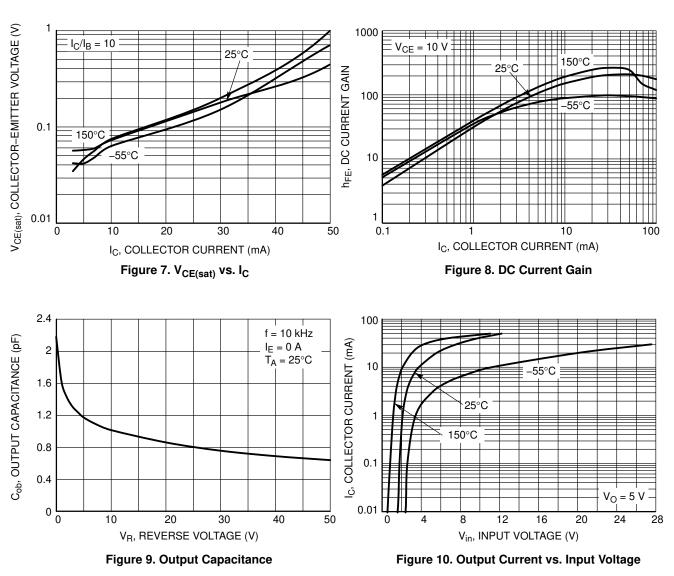
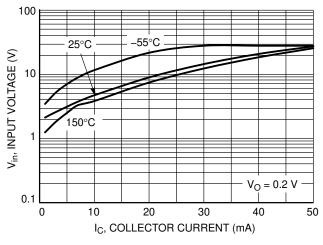


Figure 6. Input Voltage vs. Output Current





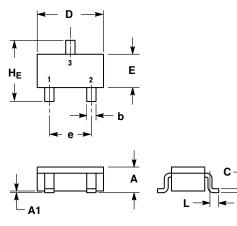




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## PACKAGE DIMENSIONS

SC-59 CASE 318D-04 ISSUE H



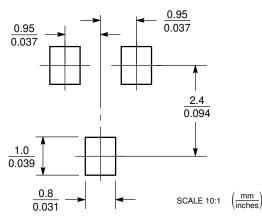
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	М	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.00	1.15	1.30	0.039	0.045	0.051	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.35	0.43	0.50	0.014	0.017	0.020	
С	0.09	0.14	0.18	0.003	0.005	0.007	
D	2.70	2.90	3.10	0.106	0.114	0.122	
E	1.30	1.50	1.70	0.051	0.059	0.067	
е	1.70	1.90	2.10	0.067	0.075	0.083	
L	0.20	0.40	0.60	0.008	0.016	0.024	
HE	2.50	2.80	3.00	0.099	0.110	0.118	

STYLE 1: PIN 1. BASE

2. EMITTER 3. COLLECTOR

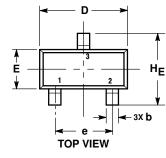
## **SOLDERING FOOTPRINT\***

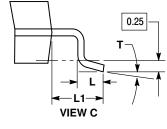


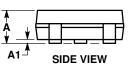
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

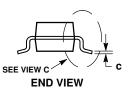
## PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR** 









NOTES:

- NOTES:
   DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
   MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF

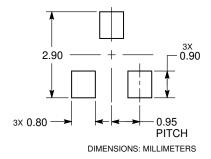
THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

STYLE 6: PIN 1. BASE

2. EMITTER
 3. COLLECTOR

RECOMMENDED **SOLDERING FOOTPRINT\*** 



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

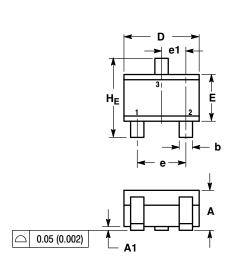
## PACKAGE DIMENSIONS

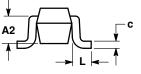
SC-70 (SOT-323) CASE 419-04 ISSUE N



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

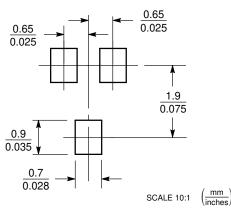
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2		0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016	
с	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.10	2.20	0.071	0.083	0.087	
E	1.15	1.24	1.35	0.045	0.049	0.053	
е	1.20	1.30	1.40	0.047	0.051	0.055	
e1		0.65 BSC		0.026 BSC			
L	0.20	0.38	0.56	0.008	0.015	0.022	
HE	2.00	2.10	2.40	0.079	0.083	0.095	
2.							





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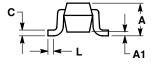
#### SOLDERING FOOTPRINT\*



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## PACKAGE DIMENSIONS

SC-75/SOT-416 **CASE 463 ISSUE F** -E-\_D\_ е b 3 PL ⊕ 0.20 (0.008) M D 0.20 (0.008) E Η<sub>E</sub>



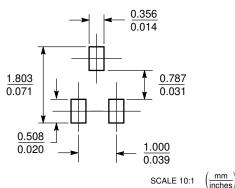
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
E	0.70	0.80	0.90	0.027	0.031	0.035
е	1	.00 BSC	;	C	.04 BSC	)
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 1: PIN 1. BASE

2. EMITTER 3. COLLECTOR

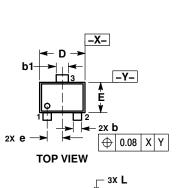
**SOLDERING FOOTPRINT\*** 

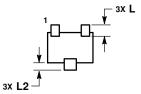


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## PACKAGE DIMENSIONS

SOT-723 CASE 631AA ISSUE D



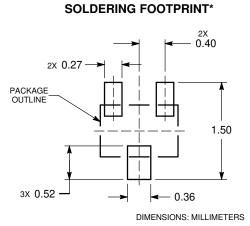


 $\mathbf{H}_{\mathbf{E}}$ -c > < SIDE VIEW

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM 3.
- THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. 4.

	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	0.45	0.50	0.55		
b	0.15	0.21	0.27		
b1	0.25	0.31	0.37		
С	0.07	0.12	0.17		
D	1.15	1.20	1.25		
Е	0.75	0.80	0.85		
е		0.40 BS0	)		
ΗE	1.15	1.20	1.25		
L		0.29 REF	-		
L2	0.15	0.20	0.25		
STYLE 1:					
PIN	1. BASE 2. EMIT 3. COLL				

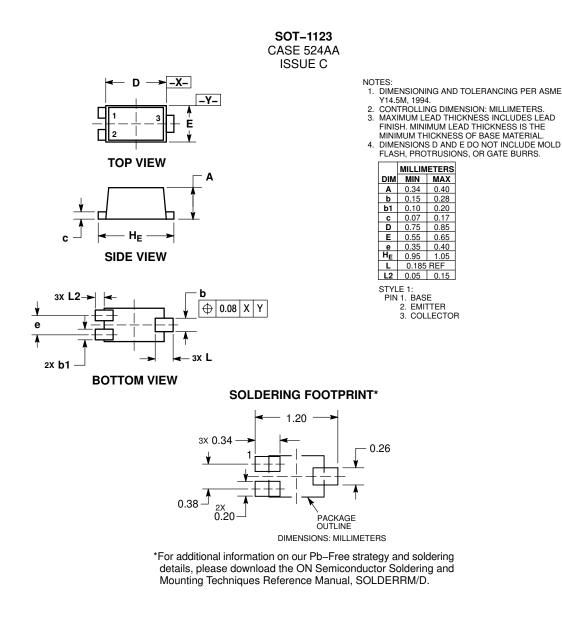
**BOTTOM VIEW** 



RECOMMENDED

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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